

# *Present status of polaritonic nonlinearities in planar III-nitride microcavities*

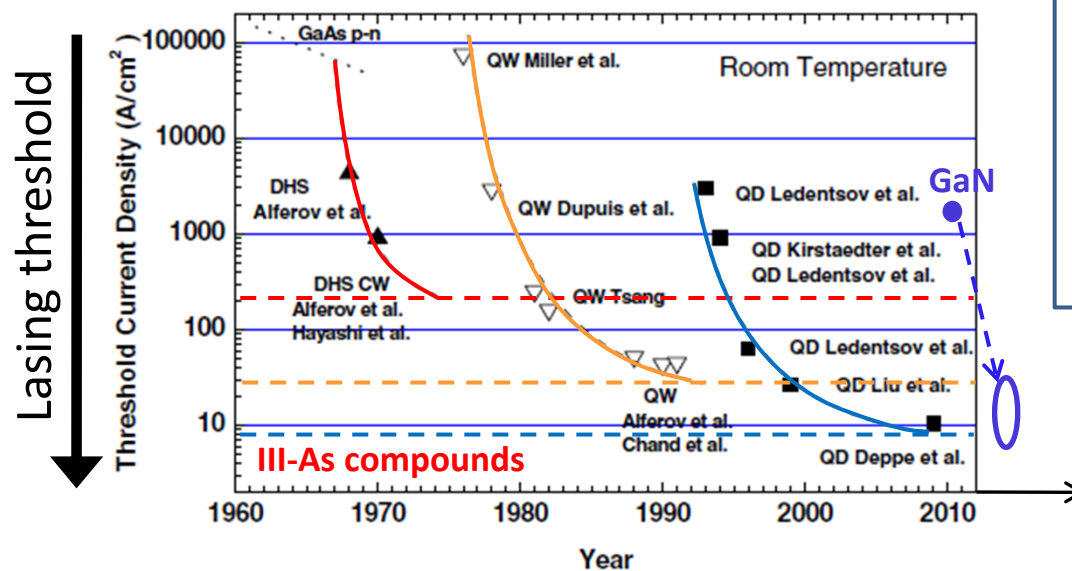
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SWITZERLAND**

# Motivations

## Fundamental:

Study of bosonic condensation phenomena up to room temperature



Wide band gap semiconductors  $\Rightarrow$  large effective masses

$\Rightarrow$  high threshold current density for lasing, best GaN edge-emitting QW LDs (Nichia/Samsung)  $\sim 1\text{--}2 \text{ kA/cm}^2$

## What could be the next step?

$\Rightarrow$  GaN polariton LDs [SST 26, 014030 \(2011\)](#)

Cf. talk Marlene Glauser

[N. N. Ledentsov, SST 26, 014001 \(2011\)](#)

## Applied:

Achieve room temperature electrical injection of cavity polaritons characterized with an ultra-low effective mass

$\Rightarrow$  Low threshold “lasers” without population inversion

[A. Imamoglu et al., PRA 53, 4250 \(1996\)](#)

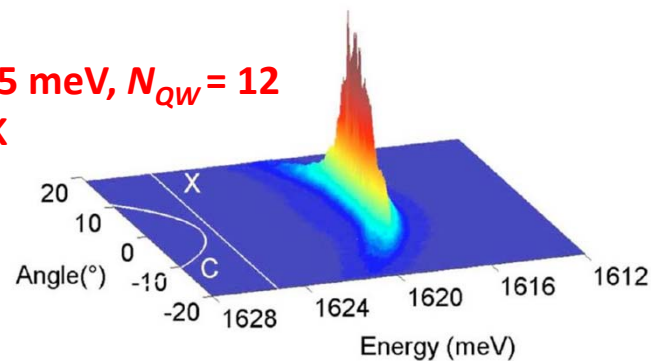
# Outline

- Polariton condensation in planar microcavities: role of the detuning  $\delta$  and temperature
- Impact of biexcitons on the relaxation mechanisms of polaritons
- A few hints on renormalization effects in III-nitride microcavities
- Conclusion and perspectives

# Polariton nonlinearities in planar microcavities

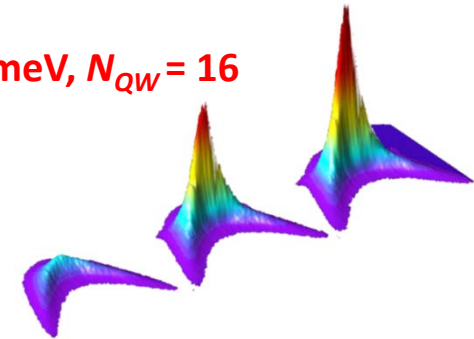
## GaAs

$\Omega_{\text{VRS}} \sim 15 \text{ meV}$ ,  $N_{\text{QW}} = 12$   
 $T_c \sim 40 \text{ K}$

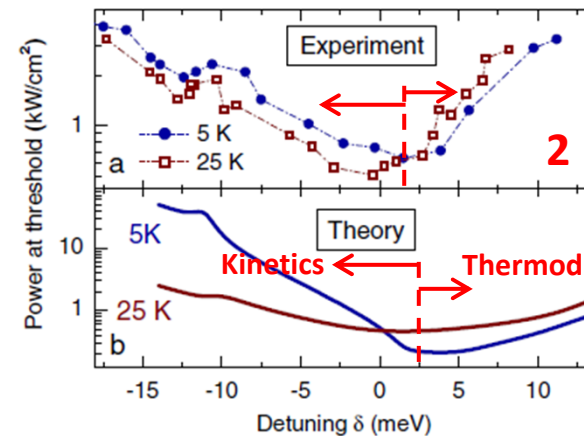
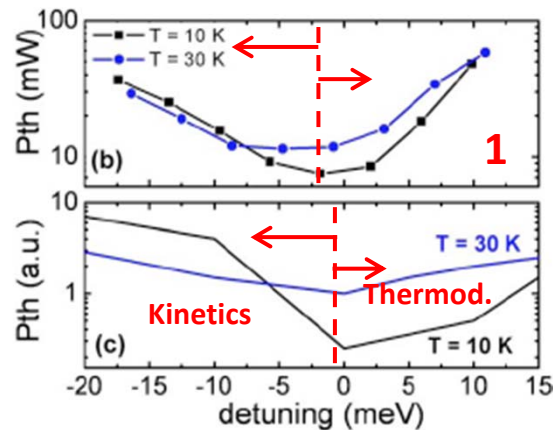


## CdTe

$\Omega_{\text{VRS}} \sim 26 \text{ meV}$ ,  $N_{\text{QW}} = 16$   
 $T_c \sim 50 \text{ K}$

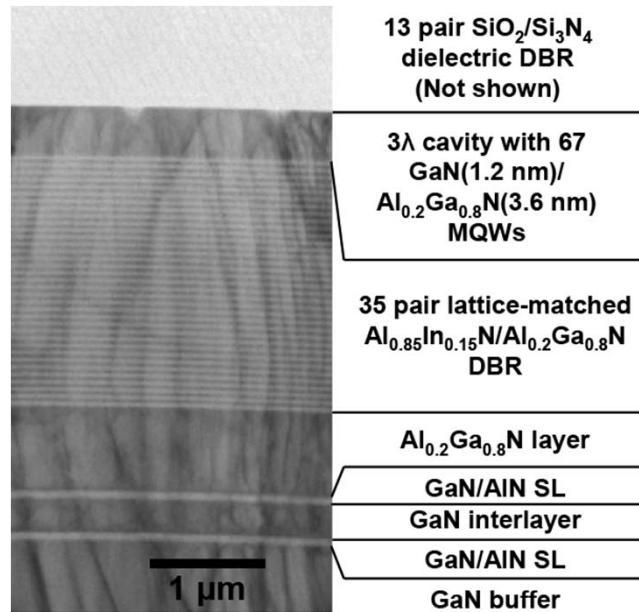


- Relaxation bottleneck to overcome
- Key role of cavity photon lifetime to achieve spontaneous condensation
- Large QW number to reduce the exciton density per well

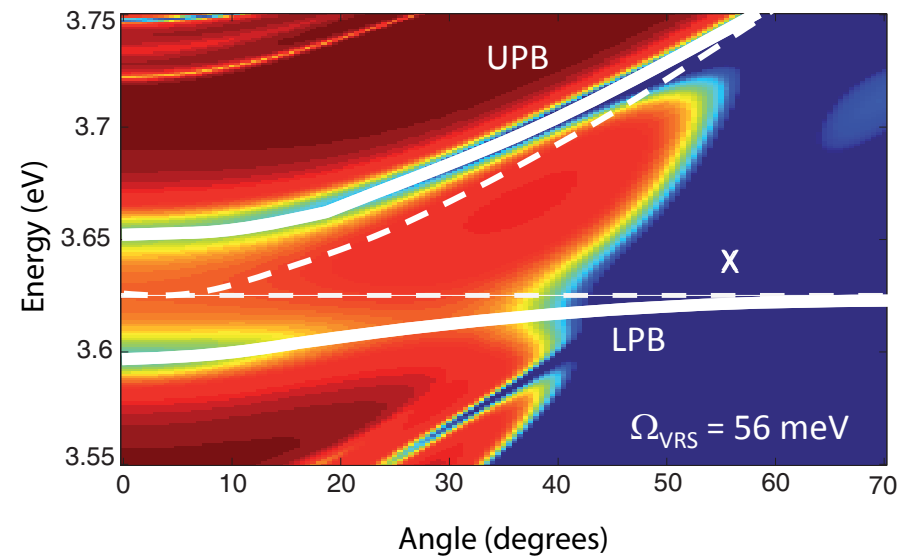


- Temperature-dependent optimum  $\delta$  but limited  $\Delta T$  range accessible

# Planar III-N microcavity for polariton studies



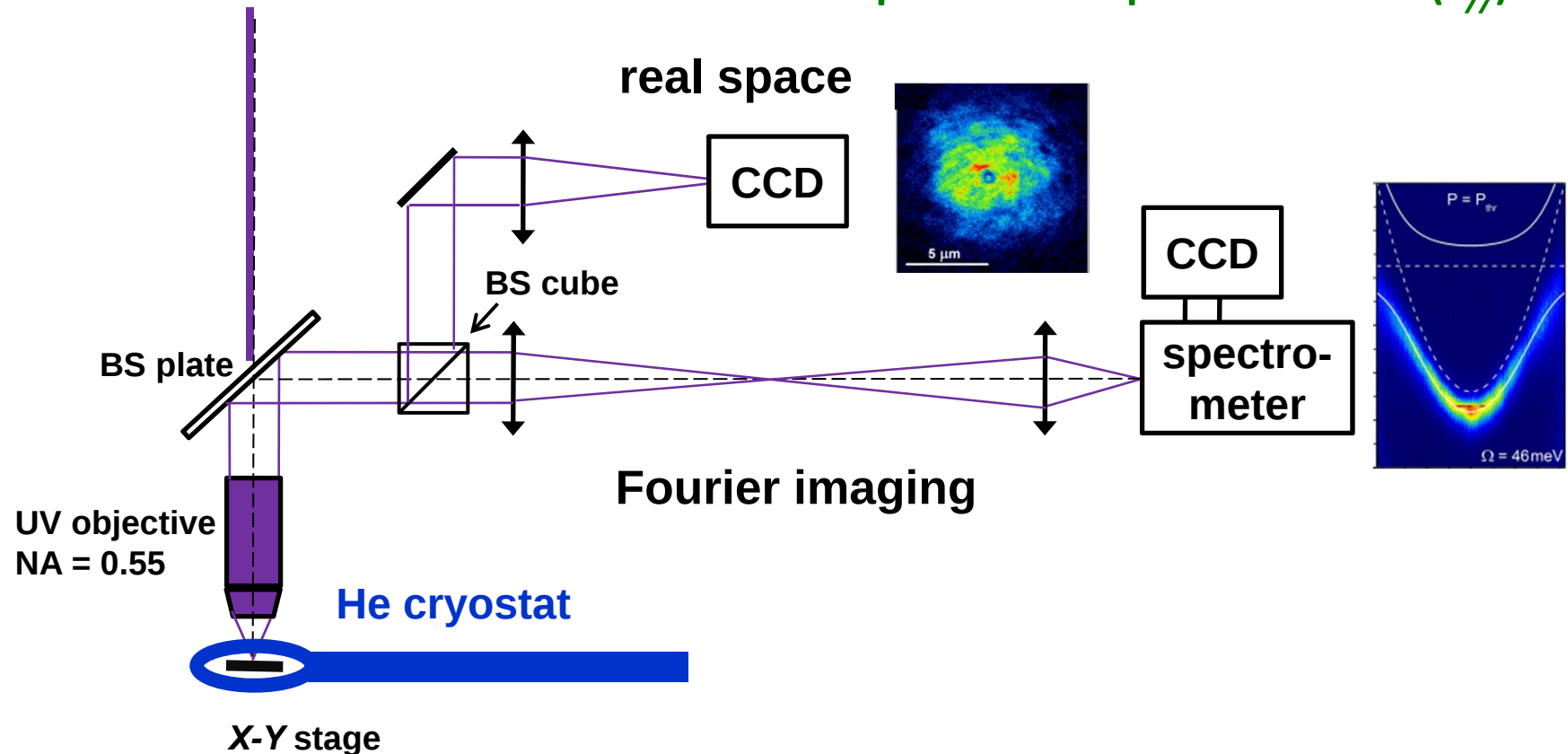
**Large QW number to  
increase Rabi splitting**



# Experimental setup

## 1- Fourier PL setup: Ar<sup>+</sup> (244 nm, cw) or Nd:YAG (266 nm, quasi-cw)

Access to the polariton dispersion curve  $E(k_{//})$



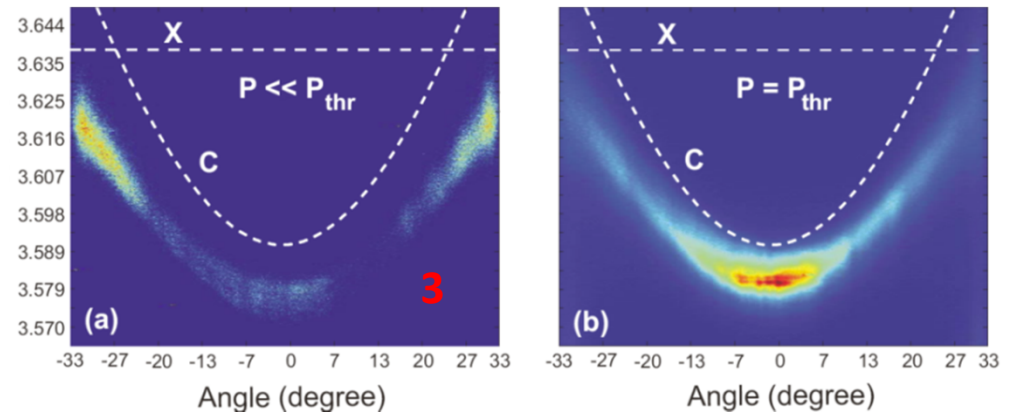
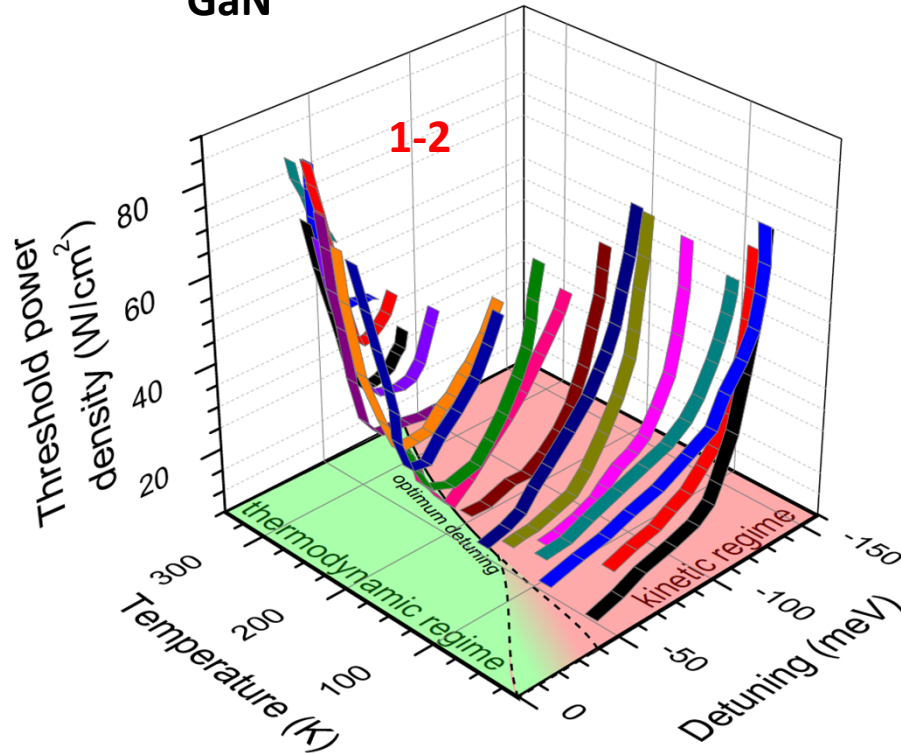
## 2- Time-resolved PL setup: Ti:sapphire (280 nm, 2 ps) + monochrom. + streak camera

Temporal evolution of the PL at  $k_{//} = 0$

# Polariton condensation phase diagram

$(\delta, T, P_{thr})$  diagram<sup>1-2</sup>

GaN



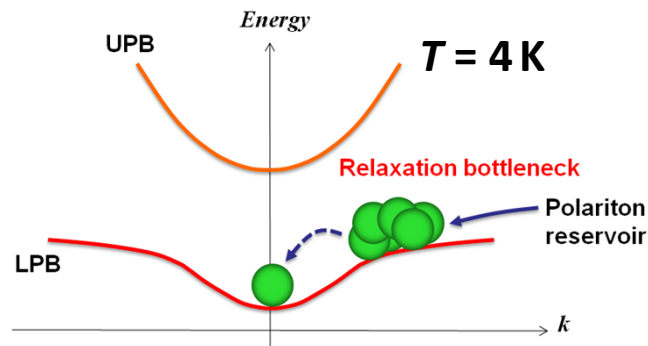
Thermalized population in the vicinity of the ground state with  $T_{eff} = 300 \pm 10$  K  
 $\Rightarrow$  signature of nonequilibrium polariton BEC at room temperature

# Polariton condensation phase diagram

Large negative detuning and low temperature

- inefficient polariton relaxation

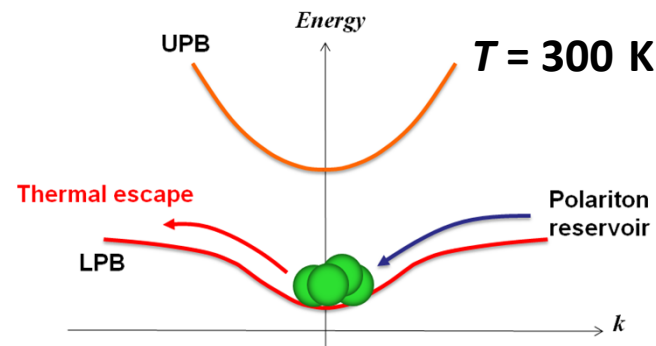
→ increasing threshold (kinetic regime)



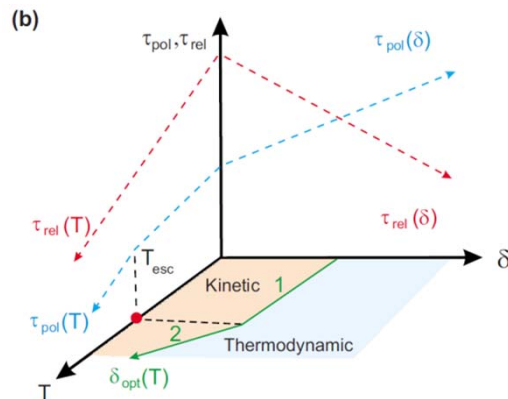
Less negative detuning and elevated temperatures

- enhanced scattering efficiency

→ decreasing threshold (toward/or thermod. regime)

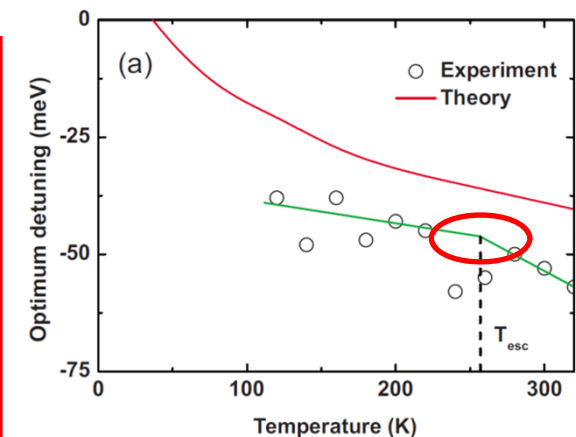


Competition between kinetic and thermodynamic condensation regimes: impact of phonon scattering term  $\Rightarrow$  shift of  $\delta_{\text{opt}}(T)$  toward more negative  $\delta$  values with increasing  $T(K)^{1-2}$



Extra kink observed in the evolution of  $\delta_{\text{opt}}(T)$  once escape from parabolic region of the LPB is allowed<sup>1-2</sup>

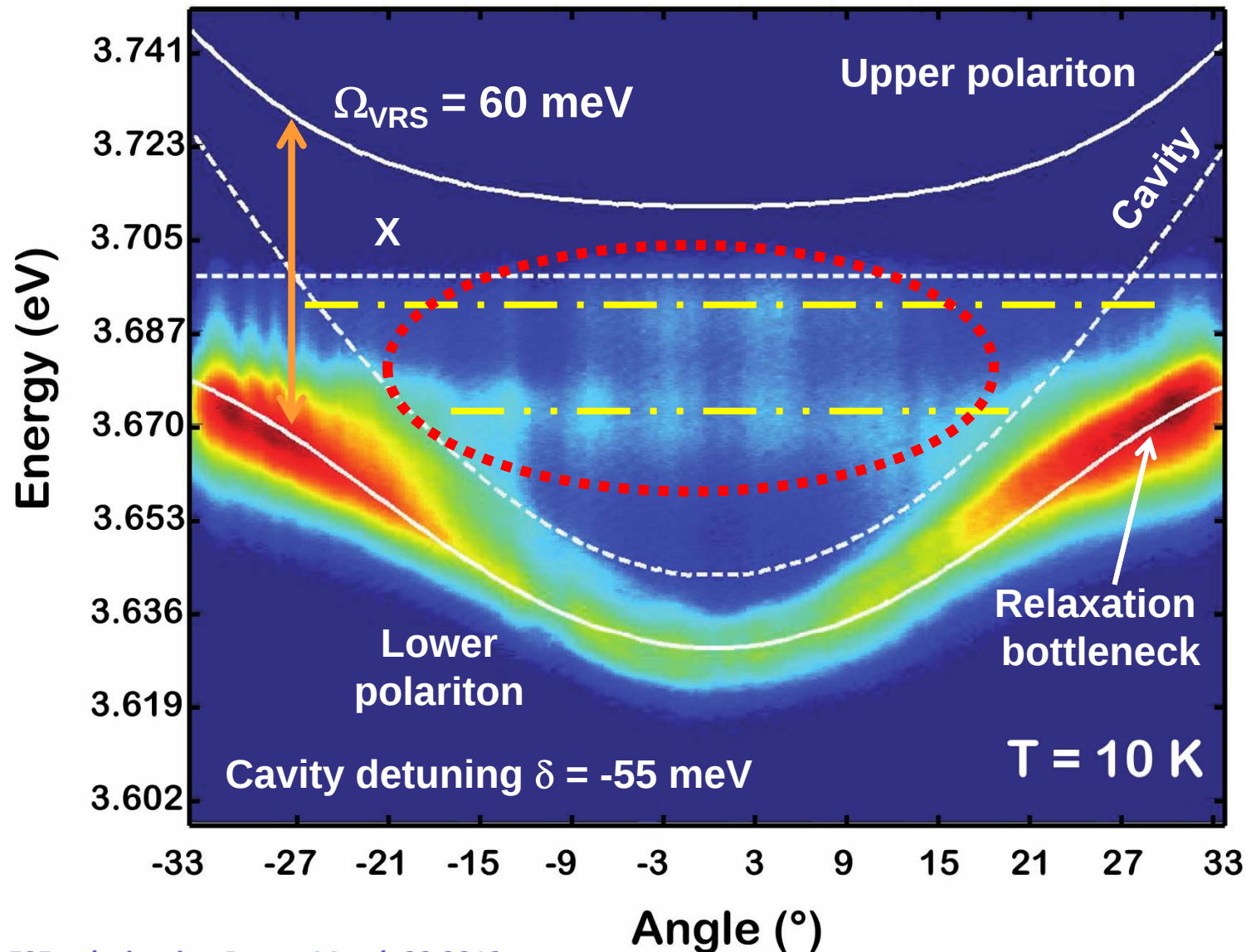
$\Rightarrow$  thermal detrapping from polariton ground state (specific feature due to matter-like character of polaritons)



# Outline

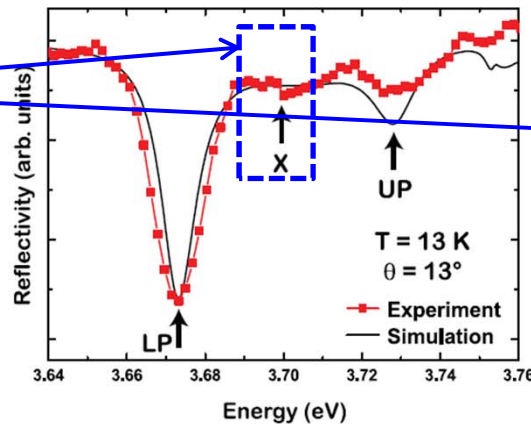
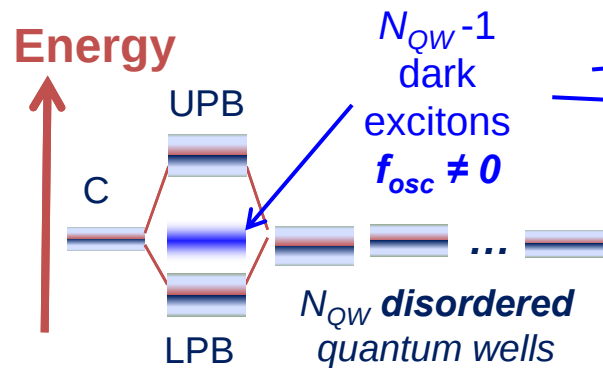
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# Fourier imaging spectroscopy: accurate farfield emission pattern

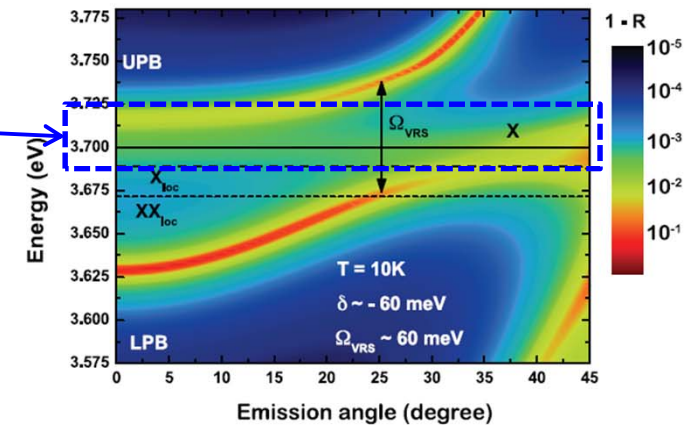


Two  
unidentified  
PL lines!

# Dark excitons in real multiple QW microcavities



Transfer matrix simulations

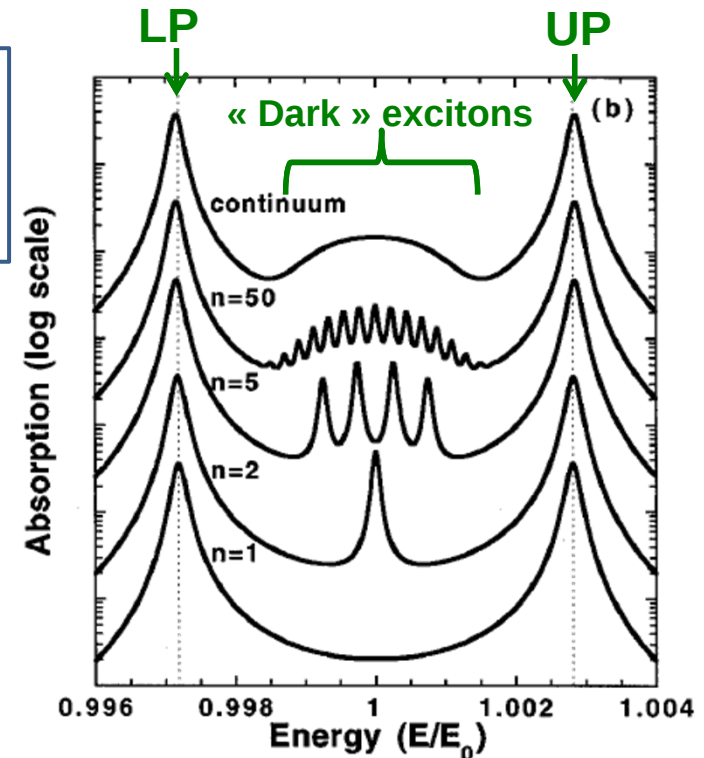


In presence of *disorder*, redistribution of the oscillator strength from the polaritons to the dark modes

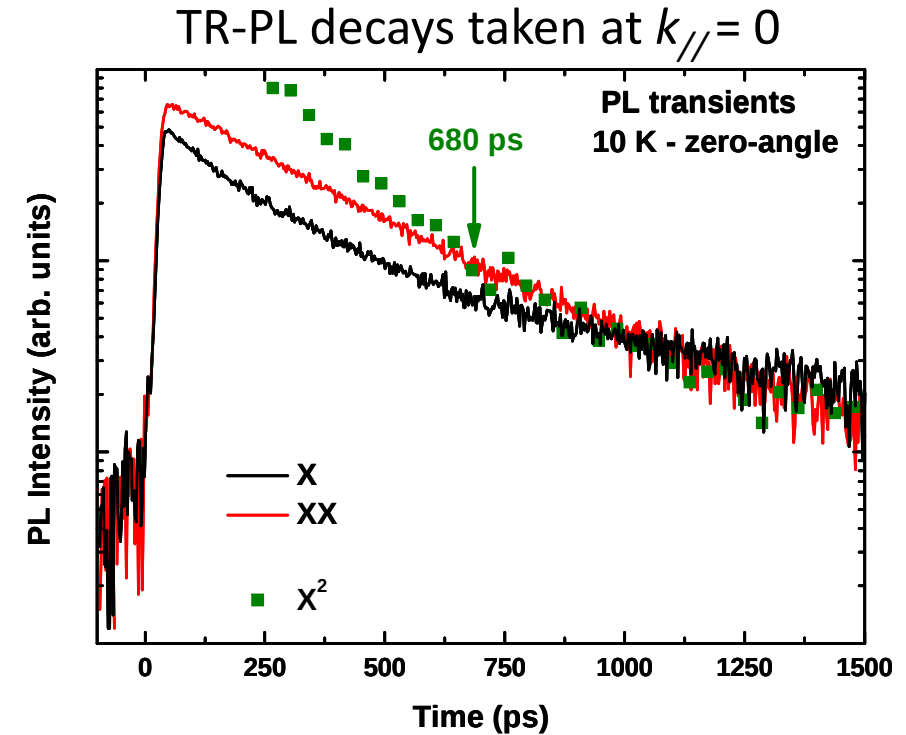
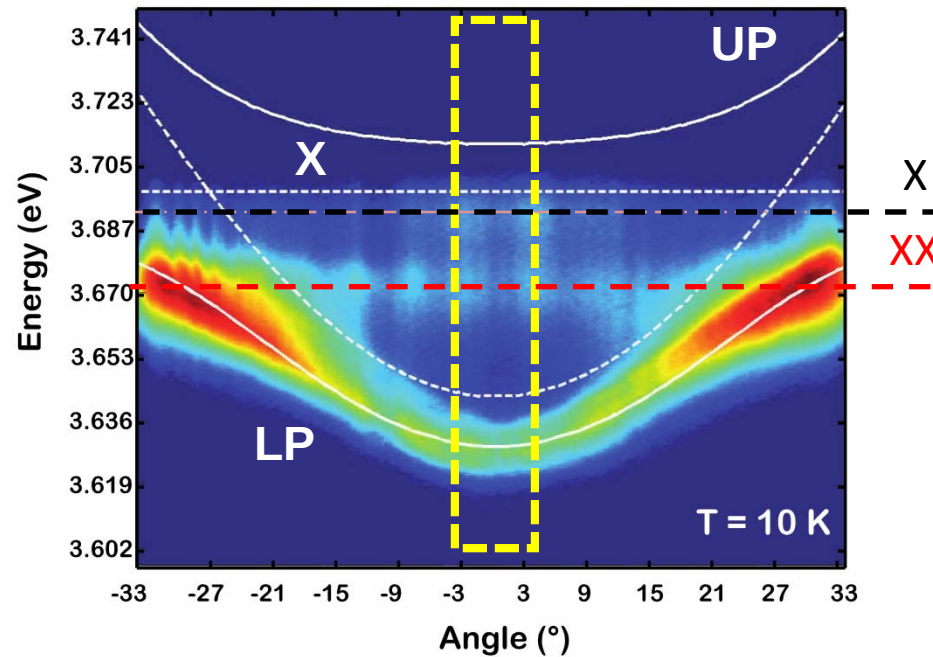
R. Houdré *et al.*, Phys. Rev. A 53, 2711 (1996)

Dark excitons can bind to form cavity biexcitons

G. C. La Rocca *et al.*, J. Opt. Soc. Am. B 15, 652 (1998)



# Exciton and biexciton dynamics



At quasi-thermal equilibrium

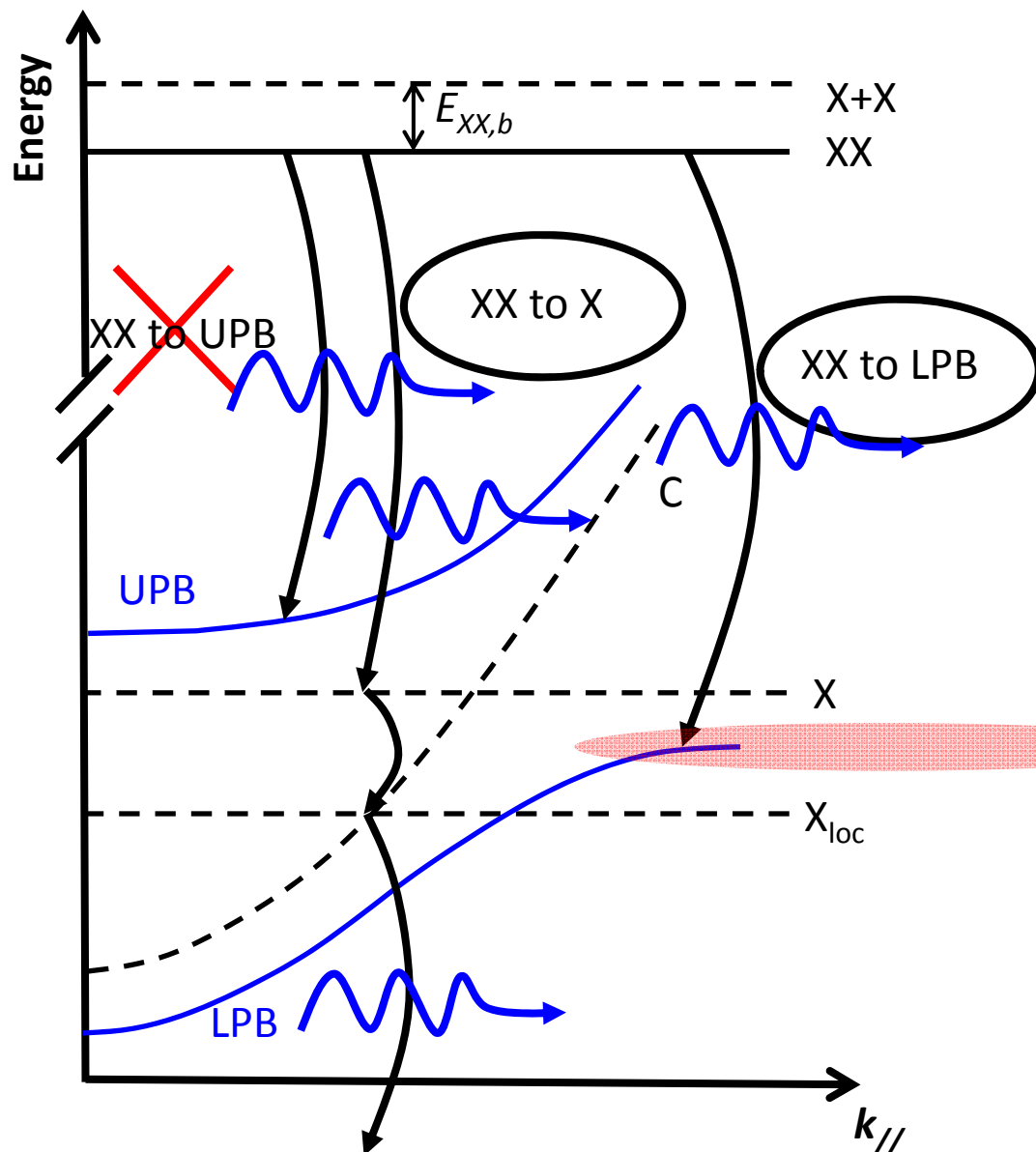


$$I_{XX} \propto I_X^2$$

## Observation of “cavity biexcitons”

Do biexcitons play a role in the relaxation mechanisms of polaritons?

## Biexciton luminescence in the full cavity



Possible cavity biexciton radiative dissociation channels:

$XX \rightarrow \text{photon} + \text{LPB}$

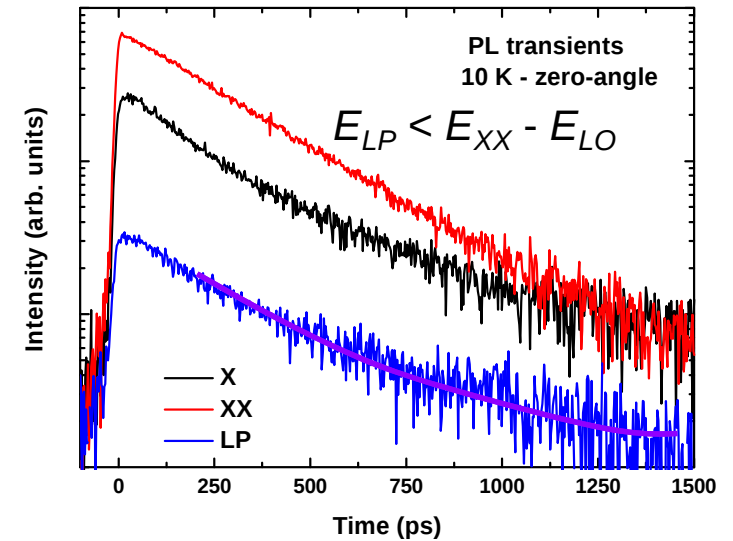
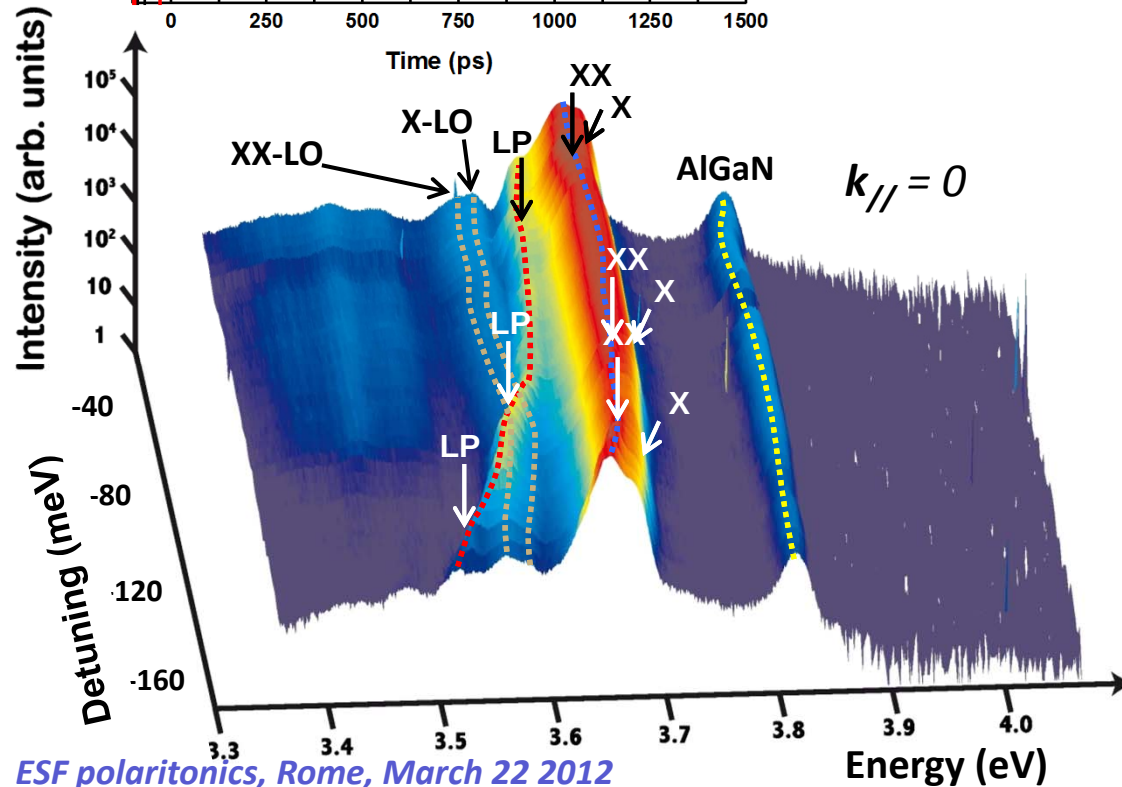
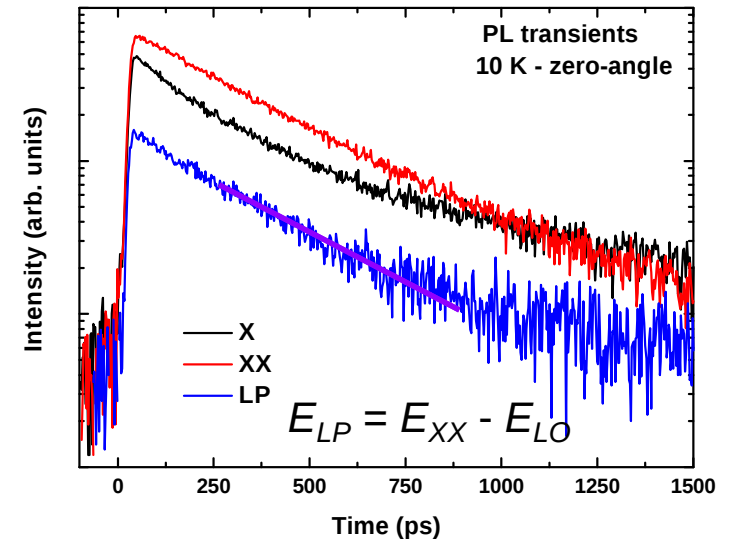
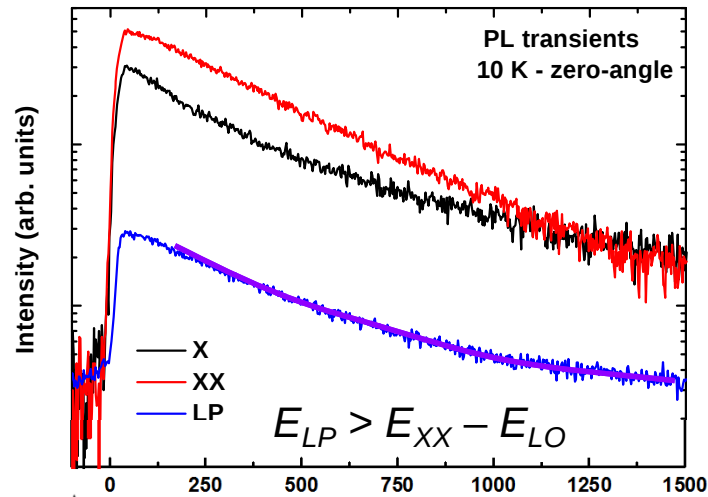
~~$XX \rightarrow \text{photon} + \text{UPB}$~~

$XX \rightarrow \text{photon} + X$

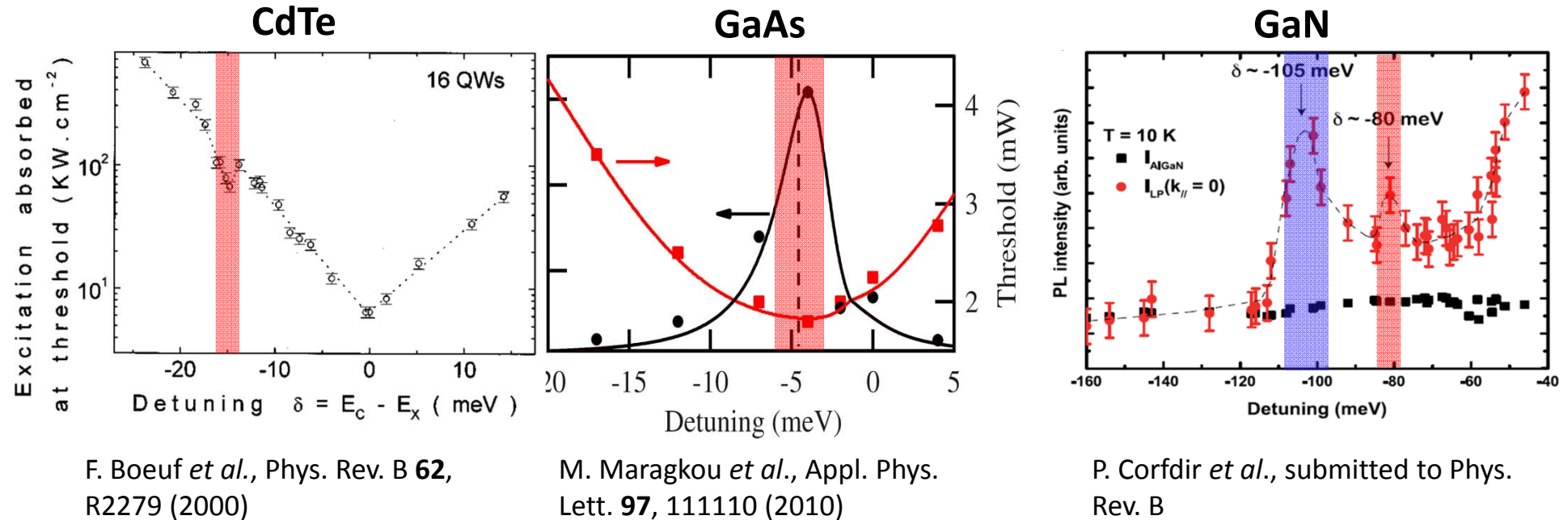
Uncoupled excitons get localized and recombine

LPs accumulate in the reservoir

# LPB relaxation dynamics



# Enhanced relaxation efficiency



## GaAs, CdTe and GaN

Increased LP relaxation efficiency when  $E_x - E_{LPB}(k_{//} = 0) = \hbar\omega_{LO}$

## GaN only

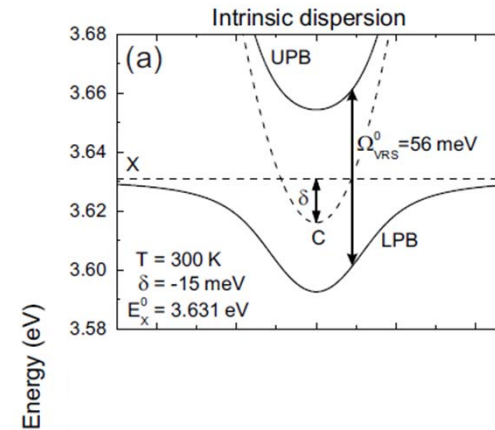
Increased LP relaxation efficiency when  $E_{xx} - E_{LPB}(k_{//} = 0) = \hbar\omega_{LO}$

Extra polariton relaxation channel mediated by cavity biexcitons

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# Renormalization of polariton branches: the standard picture

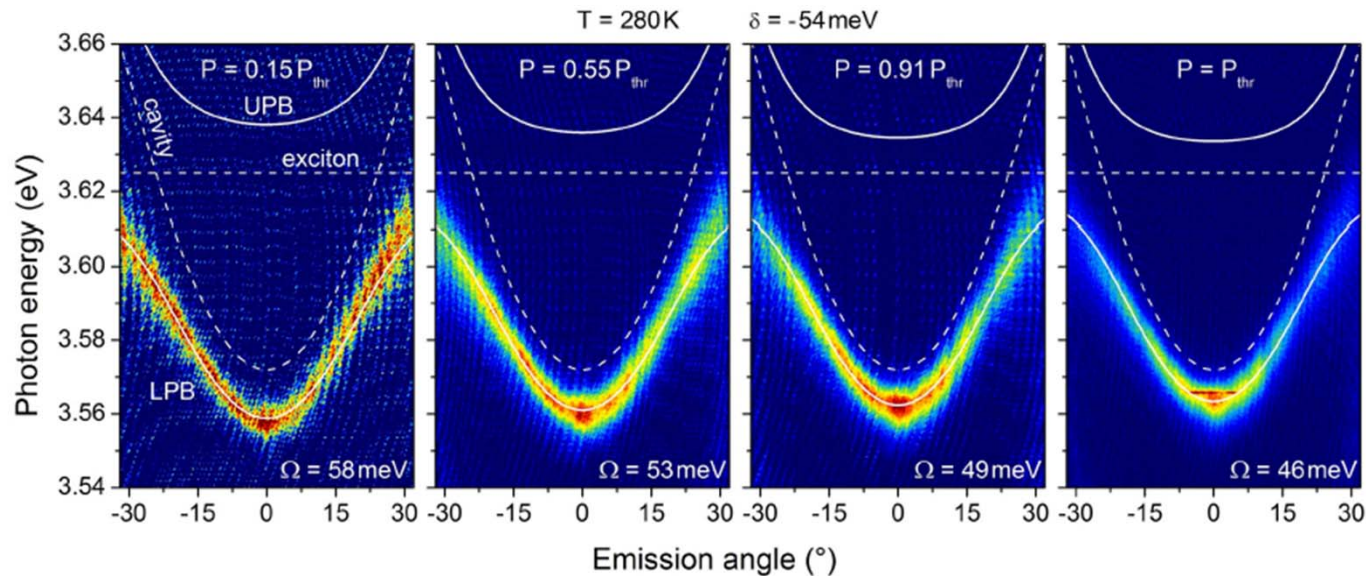


## Renormalized dispersion curve

$$\tilde{E}_{LPB/UPB}(k_{//}, \delta, n) = \frac{1}{2} \left[ E_c(k_{//}) + E_x(k_{//}) + \delta E_x(n) \right] - \frac{1}{2} \sqrt{\left( E_c(k_{//}) - E_x(k_{//}) - \delta E_x(n) \right)^2 + 4g^2(n)}$$

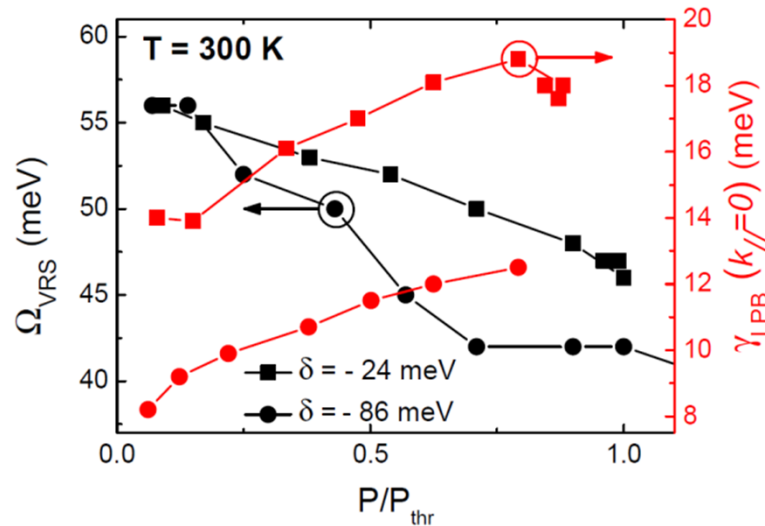
Nearly rigid blueshift of LPB and predicted linear shift of the LPB ground state with  $n$

## Renormalization of polariton branches: experimental facts

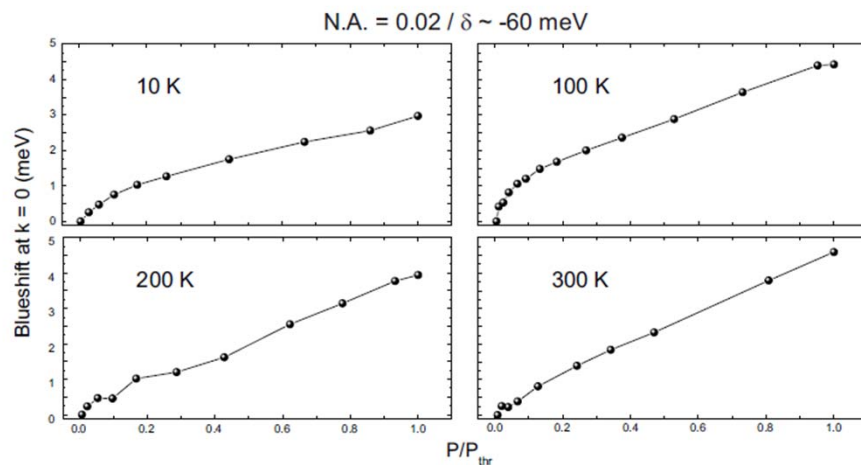


- Nearly no change observed at large  $k_{//} \Rightarrow$  saturation is the dominant renormalization effect
- $\Omega_{VRS}$  extracted from coupled oscillator model with constant  $E_x$  and  $E_c$  values
- $\Omega_{VRS}$  decreased by 20% between  $0.15$  and  $1 P_{thr}$

# Renormalization of polariton branches: impact of $\delta$ and $T$



- Saturation effects seem to decrease with increasing  $\delta$  values!
- Slow down of  $\Omega_{\text{VRS}}$  decrease when crossing  $P_{\text{thr}}$



- Blueshift at  $k_{\parallel} = 0$  showing a clear deviation from linearity for  $T < 200$  K
- Possible role of biexcitons ( $E_{\text{xx}}^b \sim 22$  meV) in a system dominated by saturation effects (GaAs model not applicable)

$\Rightarrow$  several remaining open questions likely due to specificities of saturation effects in a system with small  $a_B^{2D}$ !

## Conclusion and perspectives

- Polariton condensation phase diagram from 4 to 340 K in GaN MQW microcavity ([access to kinetic and thermodynamic relaxation regimes](#))
  - Experimental signature of [biexciton-mediated polariton relaxation](#)
  - [Anomalous renormalization behavior](#) (sublinear blueshift of LPB), key role of saturation effects + biexcitons?
- 
- Study the properties of [polariton condensates](#) over a wide range of temperatures including [renormalization](#), [biexcitonic effects](#)
  - [Electrical injection of polaritons](#) in III-N microcavities (Marlene Glauser)
  - System *a priori* suitable for (i) investigating [ultrafast OPA](#) and [OPO](#) properties @ 300 K (solitons?), (ii) realizing [coherent THz light emitters](#) (nonpolar microcavities)

# Acknowledgments

- PhDs: J. Levrat, G. Rossbach, M. Glauser, G. Christmann (Cambridge, UK)
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**Thank you for your attention!**



## Enhanced relaxation efficiency

